

isc N-Channel MOSFET Transistor

IRLI2910, IIRLI2910

FEATURES

- Low drain-source on-resistance:
 R_{DS}(on) ≤ 26mΩ (max)
- Enhancement mode
- · Fast Switching Speed
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

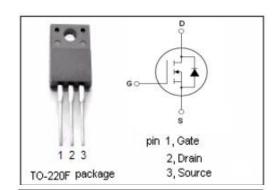
• It is intended for general purpose switching applications

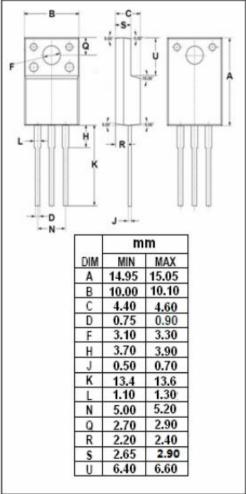
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	100	V
V _{GS}	Gate-Source Voltage	±16	V
I _D	Drain Current-Continuous	31	А
I _{DM}	Drain Current-Single Pulsed	190	А
P_D	Total Dissipation @T _C =25°C	63	W
Tj	Max. Operating Junction Temperature	175	${\mathbb C}$
T _{stg}	Storage Temperature	-55~175	$^{\circ}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	2.4	°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT			
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =0.25mA	100			V			
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	V_{DS} = V_{GS} ; I_D =0.25mA	1.0		2.0	V			
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =16A			26	mΩ			
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±16V;V _{DS} = 0V			±100	nA			
I _{DSS}	Drain-Source Leakage Current	V _{DS} =100V; V _{GS} = 0V V _{DS} =80V; V _{GS} = 0V;Tj=125°C			25 250	μА			
V_{SD}	Diode forward voltage	I _{DR} =16A, V _{GS} = 0 V			1.3	V			

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